



## JST12F-600SW 12A TRIAC

Rev.A.1.0

The JST12F-600SW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. JST12F-600SW snubberless triac is especially recommended for use on inductive loads. It can be driven directly through the MCU I/O port. By using an external plastic package, JST12F-600SW provides a rated insulation voltage of 2000 VRMS, complying with UL standards (File ref: E252906). Package TO-220F is RoHS compliant.

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	
Operating junction temperature range	$T_j$	-40-125	
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )	$V_{DRM}$	600	V

Average gate power dissipation ( $T_j=125$ )	$P_{G(AV)}$	0.5	W
Peak gate power	$P_{GM}$	10	W
Peak pulse voltage ( $T_j=25$ ; non-repetitive,off-state;FIG.7)	$V_{pp}$	4	kV

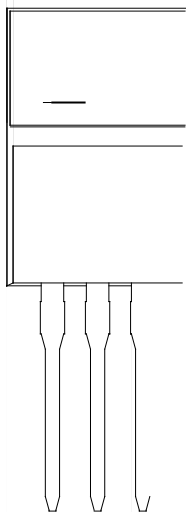
( $T_j=25$  unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
$I_{GT}$	$V_D=12V R_L=33\Omega$	- -	MAX.	10	mA
$V_{GT}$		- -	MAX.	1	V
$V_{GD}$	$V_D=V_{DRM} T_j=125$ $R_L=3.3K\Omega$	- -	MIN.	0.2	V
$I_L$	$I_G=1.2I_{GT}$	-	MAX.	25	mA
				30	
$I_H$	$I_T=500mA$		MAX.	15	mA
$dV/dt$	$V_D=400V$ Gate Open $T_j=125$		MIN.	500	V/ $\mu s$
$(dI/dt)_c$	$(dV/dt)_c=10V/\mu s T_j=125$		MIN.	3	A/ms
$t_{on}$	$I_G=20mA I_A=200mA I_R=20mA$ $T_j=25$		TYP.	2.5	$\mu s$
$t_{off}$				25	

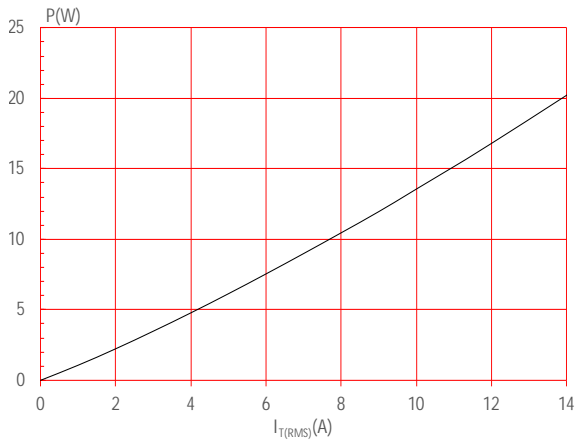
Symbol	Parameter		Value(MAX.)	Unit
$V_{TM}$	$I_{TM}=17A t_p=380\mu s$	$T_j=25$	1.5	V
$V_{TO}$	Threshold voltage	$T_j=125$	0.77	V
$R_D$	Dynamic resistance	$T_j=125$	35	$m\Omega$
$I_{DRM}$	$V_D=V_{DRM} V_R=V_{RRM}$	$T_j=25$	5	$\mu A$
$I_{RRM}$		$T_j=125$	0.4	mA

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	2.4	$\text{W}$
$R_{th(j-a)}$	junction to ambient (AC)	60	$\text{W}$

	<b>J</b>	<b>ST</b>	<b>12</b>	<b>F</b>	<b>-600</b>	<b>SW</b>
JieJie Microelectronics Co., Ltd.		Triacs				
		<u>IT(RMS):12A</u>				
			<u>F:TO-220F(Ins)</u>			
						<u>SW:IGT1-3 10mA</u>
					<u>600:VDRM /VRRM 600V</u>	



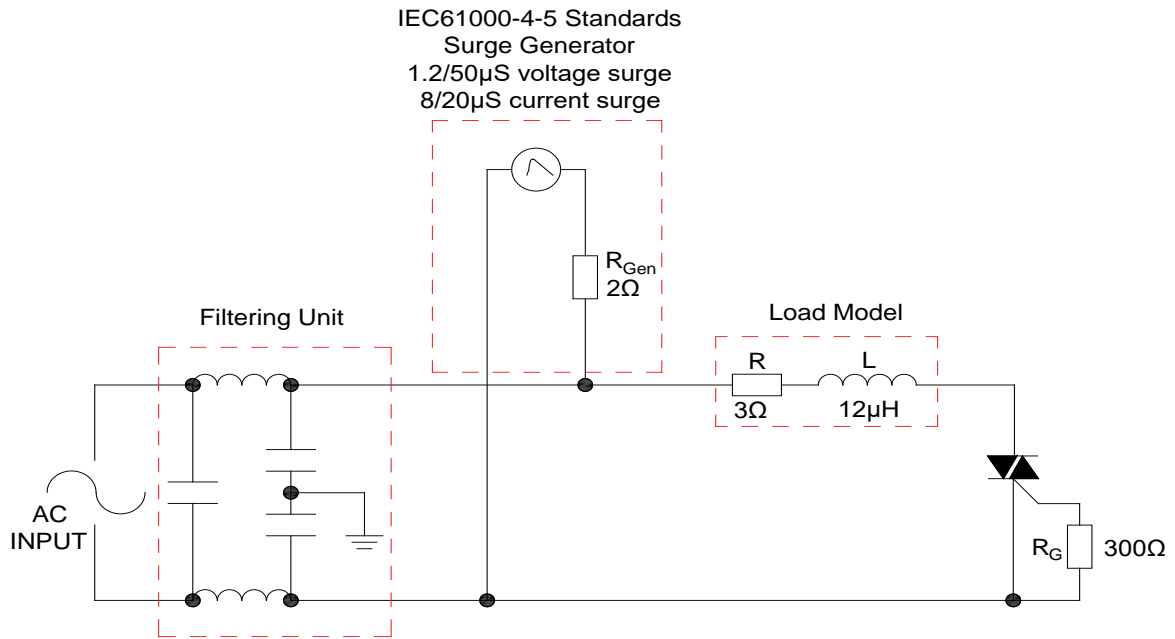
**FIG.1** Maximum power dissipation versus RMS on-state current



**FIG.2:** RMS on-state current versus case temperature



FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



Refer to Instructions for installation of plastic-sealed in-line power devices released by JieJie

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		- -			
JST12F-600SW	600	10	TO-220F(Ins)	50	Tube

**Document Revision History**

Date	Revision	Changes
Apr.11, 2023	A.1.0	Last updated

**JST12F-600SW**

**Jie**

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